

isc Silicon NPN Power Transistor

DESCRIPTION

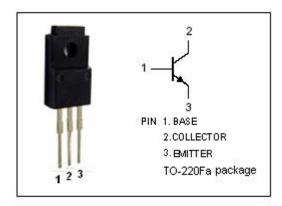
- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 0.5V(Max)@ I_C= 5A
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 80V (Min)
- · Good Linearity of hFE
- · Complement to Type 2SB946
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

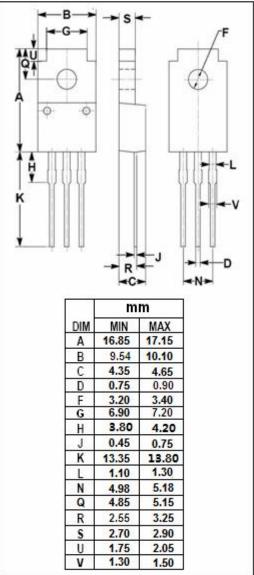


· Designed for power switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	130	V	
V _{CEO}	Collector-Emitter Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	7	V	
lc	Collector Current-Continuous 7		А	
I _{CM}	Collector Current-Peak 15		А	
Pc	Collector Power Dissipation @ T _C =25℃	40	W	
	Collector Power Dissipation @ T _a =25℃	2		
TJ	Junction Temperature	150 ℃		
T _{stg}	Storage Temperature Range -55~150		°C	







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2SD1271

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	80			V	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 0.25A			0.5	V	
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 0.25A			1.5	V	
Ісво	Collector Cutoff Current V _{CB} = 100V; I _E = 0				10	μ А	
I _{ЕВО}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			50	μ А	
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 2V	45				
h _{FE-2}	DC Current Gain	I _C = 3A; V _{CE} = 2V	90		260		
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 10V; f= 10MHz		30		MHz	
Switching times							
ton	Turn-on Time			0.5		μs	
t _{stg}	Storage Time	I _C = 3A; I _{B1} = I _{B2} = 0.3A; V _{CC} = 50V		1.5		μS	
t _f	Fall Time			0.1		μ S	

♦ h_{FE-2} classifications

Q	Р		
90-180	130-260		

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